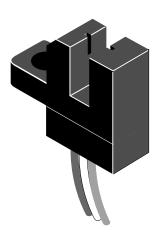


- 1. Dimensions for all drawings are in inches (millimeters).
- 2. Tolerance of ± .010 (.25) on all non-nominal dimensions unless otherwise specified.
- 3. Wire gauge: 24 AWG, 7 strand, pre-tinned copper.



FEATURES

- No contact switching
- Mounting tab
- Wire leads for remote connection
- 3 mm slot
- Output configuration: Inverter open-collector
- TTL/CMOS compatible output
- Aperture width: .014"

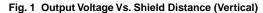
NOTES (Applies to Max Ratings and Characteristics Tables.)

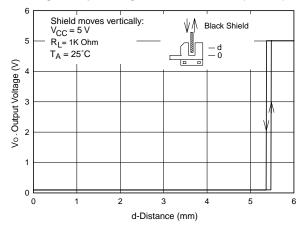
- 1. Derate power dissipation linearly 1.67 mW/°C above 25°C.
- 2. Derate power dissipation linearly 2.50 mW/°C above 25°C.
- 3. RMA flux is recommended.
- Methanol or isopropyl alcohols are recommended as cleaning agents.

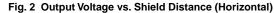
ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)						
Parameter	Symbol	Rating	Units			
Operating Temperature	T _{OPR}	-40 to +85	°C			
Storage Temperature	T _{STG}	-40 to +85	°C			
Soldering Temperature (Iron)(3,4)	T _{SOL-I}	240 for 5 sec	°C			
EMITTER						
Continuous Forward Current	I _F	50	mA			
Reverse Voltage	V _R	5	V			
Power Dissipation ⁽¹⁾	P _D	100	mW			
SENSOR						
Output Current	Io	50	mA			
Supply Voltage	V _{CC}	16	V			
Output Voltage	Vo	30	V			
Power Dissipation(2)	P _D	150	mW			



ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C)								
PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNITS		
Operating Supply Voltage		V_{CC}	4.5	_	16	V		
INPUT DIODE								
Forward Voltage	$I_F = 20 \text{ mA}$	V_{F}	_	_	1.7	V		
Reverse Leakage Current	V _R = 5 V	I _R	_	_	10	μΑ		
COUPLED								
Operating Supply Current	$V_{CC} = 16 V$	I_{CC}	_	_	12	mA		
Low Level Output Voltage	V_{CC} = 5 V, R_L = 360 Ω	V _{OL}	_		0.4	V		
High Level Output Current	$V_{CC} = 5 \text{ V}, V_{OH} = 30 \text{ V} \text{ (Light Path Blocked)}$	I _{OH}	_	_	100	μΑ		
Hysteresis Ratio			_	1.2	_			
Propagation Delay	V_{CC} = 5 V, R_L = 360 Ω	t _{PLH,} t _{PHL}	_	5	_	μs		
Output Rise and Fall Time	V_{CC} = 5 V, R_L = 360 Ω	$t_{r,} t_{f}$		70	<u> </u>	ns		







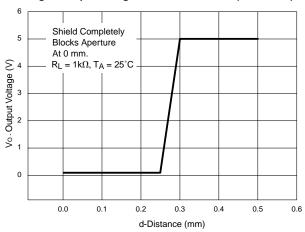




Fig. 3 Supply Current vs. Supply Voltage

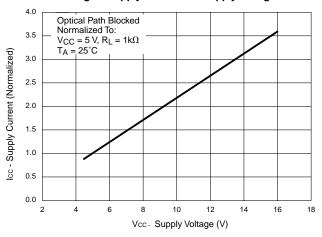


Fig. 4 Supply Current vs. Supply Voltage

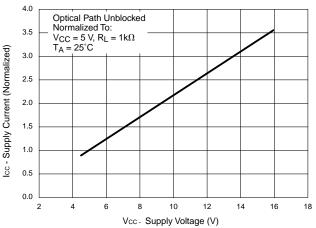


Fig. 5 Low Level Output Voltage vs. Supply Voltage

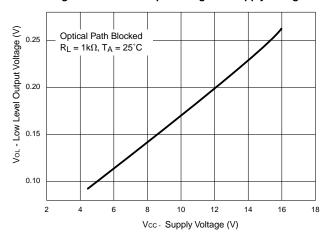


Fig. 6 Low Level Output Voltage vs. Load Resistance

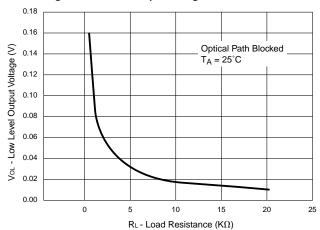




Fig. 7 Schematic

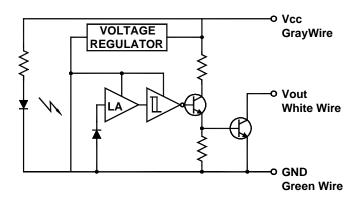
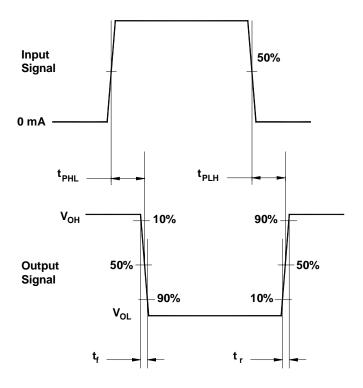


Fig. 8 Switching Test Curve for Inverters





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